

### INCHANGE SEMICONDUCTOR

### isc N-Channel MOSFET Transistor

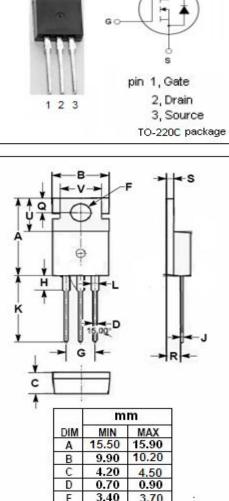
# IXTP44N10T

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#### FEATURES · Static drain-source on-resistance: $R_{DS}(on) \leq 30m\Omega @V_{GS}=10V$ · Fully characterized avalanche voltage and current 100% avalanche tested Minimum Lot-to-Lot variations for robust device performance and reliable operation 123 APPLICATION DC/DC Converters · High Current Switching Applications ABSOLUTE MAXIMUM RATINGS(Ta=25°C) SYMBOL PARAMETER VALUE UNIT VDSS **Drain-Source Voltage** 100 V V V<sub>GS</sub> Gate-Source Voltage $\pm 30$ Drain Current-Continuous 44 $I_D$ А с Drain Current-Single Pulsed 140 А **I**DM mm DIM MIN $P_{D}$ Total Dissipation @Tc=25°C W 130 15.50 А 9.90 В **Operating Junction Temperature** -55~175 °C С 4.20 Τį D 0.70 F 3.40 Storage Temperature -40~175 °C G 4.98 Tstg 5.18Н 2.68 2.90J 0.44 0.60 13.00 K 13.40 THERMAL CHARACTERISTICS 1.10 1.45 L

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SYMBOL	PARAMETER	MAX	UNIT
R <sub>th(j-c)</sub>	Junction-to-case thermal resistance	1.15	°C/W



2.70

2.30

1.29

6.45

8.66

2.90

2.70

1.35

6.65

8.86

Q

R

S

U

v



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#### **ELECTRICAL CHARACTERISTICS**

#### $T_{\text{C}}\text{=}25^{\circ}\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0V; ID = 250 μ A	100		V
$V_{GS(th)}$	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; ID = 25 μ A	2.5	4.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> = 22A		30	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> =0V		±100	nA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0V		1	- μ <b>Α</b>
		V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0V;T <sub>J</sub> = 150°C		100	
Vsd	Diode forward voltage	I <sub>F</sub> = 25A; V <sub>GS</sub> = 0V		1.1	V

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